## MJE243 - NPN, MJE253 - PNP

# **Complementary Silicon Power Plastic Transistors**

These devices are designed for low power audio amplifier and low-current, high-speed switching applications.

#### **Features**

• High Collector-Emitter Sustaining Voltage -

 $V_{CEO(sus)} = 100 \text{ Vdc (Min)}$ 

• High DC Current Gain @ I<sub>C</sub> = 200 mAdc

 $h_{FE} = 40 - 200$ = 40 - 120

• Low Collector-Emitter Saturation Voltage -

 $V_{CE(sat)} = 0.3 \text{ Vdc (Max)} @ I_C = 500 \text{ mAdc}$ 

• High Current Gain Bandwidth Product -

 $f_T = 40 \text{ MHz (Min)} @ I_C = 100 \text{ mAdc}$ 

• Annular Construction for Low Leakages

 $I_{CBO}$  = 100 nAdc (Max) @ Rated  $V_{CB}$ 

• Pb-Free Packages are Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	100	Vdc
Collector-Base Voltage	V <sub>CB</sub>	100	Vdc
Emitter-Base Voltage	V <sub>EB</sub>	7.0	Vdc
Collector Current – Continuous – Peak	I <sub>C</sub>	4.0 8.0	Adc
Base Current	I <sub>B</sub>	10	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	15 120	W mW/°C
Total Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$\theta_{\sf JC}$	8.34	°C/W
Thermal Resistance, Junction-to-Ambient	$\theta_{JA}$	83.4	°C/W

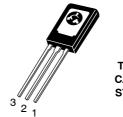
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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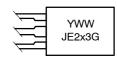
http://onsemi.com

# 4.0 AMPERES POWER TRANSISTORS COMPLEMENTARY SILICON 100 VOLTS, 15 WATTS



TO-225 CASE 77 STYLE 1

#### **MARKING DIAGRAM**



#### **ORDERING INFORMATION**

Device	Package	Shipping
MJE243	TO-225	500 Units/Box
MJE243G	TO-225 (Pb-Free)	500 Units/Box
MJE253	TO-225	500 Units/Box
MJE253G	TO-225 (Pb-Free)	500 Units/Box

**Preferred** devices are recommended choices for future use and best overall value.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### MJE243 - NPN, MJE253 - PNP

#### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	•	•		•
Collector–Emitter Sustaining Voltage $(I_C = 10 \text{ mAdc}, I_B = 0)$	V <sub>CEO(sus)</sub>	100	_	V
Collector Cutoff Current $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$ $(V_{CE} = 100 \text{ Vdc}, I_E = 0, T_C = 125 ^{\circ}\text{C})$	I <sub>CBO</sub>	- -	0.1 0.1	μA mA
Emitter Cutoff Current (V <sub>BE</sub> = 7.0 Vdc, I <sub>C</sub> = 0)	I <sub>EBO</sub>	-	0.1	μAdc
ON CHARACTERISTICS	·			
DC Current Gain ( $I_C$ = 200 mAdc, $V_{CE}$ = 1.0 Vdc) ( $I_C$ = 1.0 Adc, $V_{CE}$ = 1.0 Vdc)	h <sub>FE</sub>	40 15	180	-
Collector–Emitter Saturation Voltage ( $I_C = 500 \text{ mAdc}$ , $I_B = 50 \text{ mAdc}$ ) ( $I_C = 1.0 \text{ Adc}$ , $I_B = 100 \text{ mAdc}$ )	V <sub>CE(sat)</sub>	- -	0.3 0.6	V
Base–Emitter Saturation Voltage ( $I_C = 2.0$ Adc, $I_B = 200$ mAdc)	V <sub>BE(sat)</sub>	-	1.8	V
Base–Emitter On Voltage (I <sub>C</sub> = 500 mAdc, V <sub>CE</sub> = 1.0 Vdc)	V <sub>BE(on)</sub>	-	1.5	V
DYNAMIC CHARACTERISTICS	<u>.</u>			
Current-Gain - Bandwidth Product ( $I_C = 100 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f_{test} = 10 \text{ MHz}$ )	f <sub>T</sub>	40	_	MHz
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 0.1 MHz)	C <sub>ob</sub>	-	50	pF

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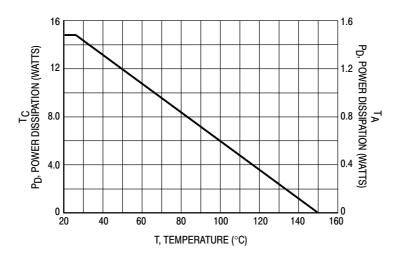


Figure 1. Power Derating

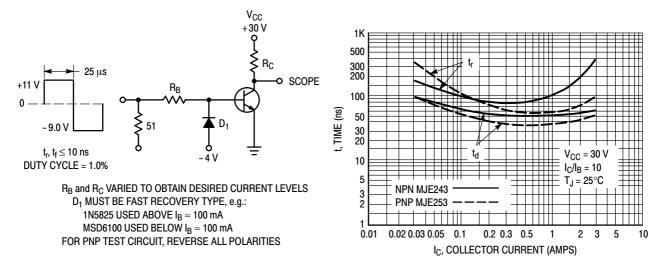


Figure 2. Switching Time Test Circuit

Figure 3. Turn-On Time

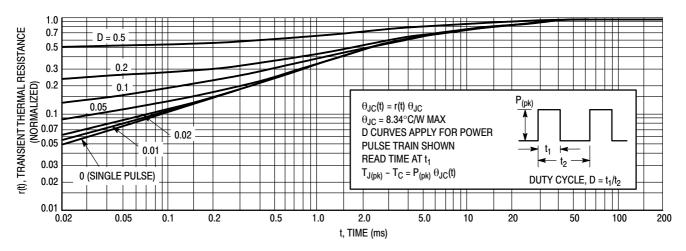


Figure 4. Thermal Response

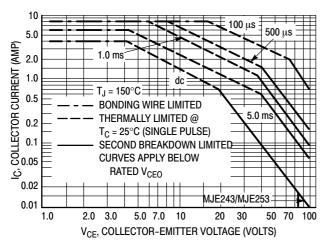


Figure 5. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C$  –  $V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on  $T_{J(pk)} = 150^{\circ}\text{C}$ ;  $T_{C}$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} \leq 150^{\circ}\text{C}$ .  $T_{J(pk)}$  may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

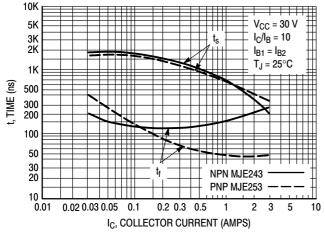


Figure 6. Turn-Off Time

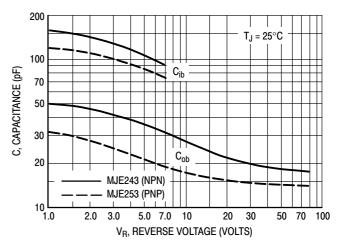


Figure 7. Capacitance

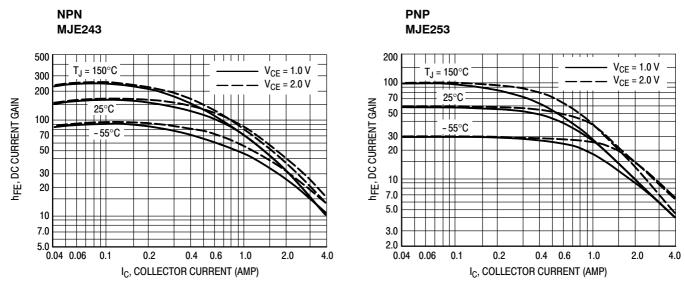


Figure 8. DC Current Gain

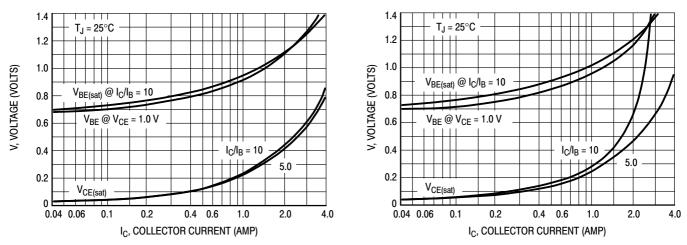


Figure 9. "On" Voltages

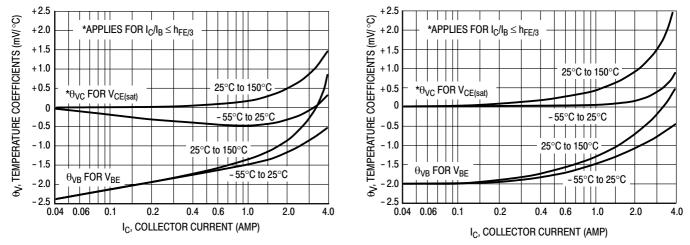
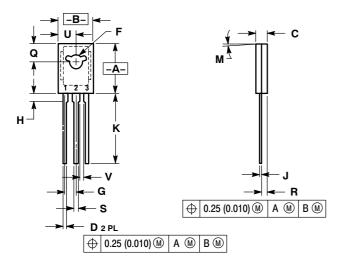


Figure 10. Temperature Coefficients

#### PACKAGE DIMENSIONS

TO-225 CASE 77-09 **ISSUE Z** 



#### NOTES:

- 11. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- 3. 077-01 THRU -08 OBSOLETE, NEW STANDARD 077-09

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.425	0.435	10.80	11.04	
В	0.295	0.305	7.50	7.74	
С	0.095	0.105	2.42	2.66	
D	0.020	0.026	0.51	0.66	
F	0.115	0.130	2.93	3.30	
G	0.094	0.094 BSC		BSC	
Н	0.050	0.095	1.27	2.41	
J	0.015	0.025	0.39	0.63	
K	0.575	0.655	14.61	16.63	
M	5° TYP		5° TYP		
Q	0.148	0.158	3.76	4.01	
R	0.045	0.065	1.15	1.65	
S	0.025	0.035	0.64	0.88	
U	0.145	0.155	3.69	3.93	
٧	0.040		1.02		

STYLE 1:

**EMITTER** PIN 1.

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